

#### **FUJI POWER MOSFET**

# Super FAP-E<sup>3</sup> series

## N-CHANNEL SILICON POWER MOSFET

#### Features

Outline Drawings [mm]

Equivalent circuit schematic

Maintains both low power loss and low noise Lower R<sub>DS</sub>(on) characteristic More controllable switching dv/dt by gate resistance Smaller V<sub>GS</sub> ringing waveform during switching Narrow band of the gate threshold voltage (3.0±0.5V) High avalanche durability

#### Applications

Switching regulators UPS (Uninterruptible Power Supply) DC-DC converters

#### Maximum Ratings and Characteristics

#### Absolute Maximum Ratings at Tc=25°C (unless otherwise specifed)

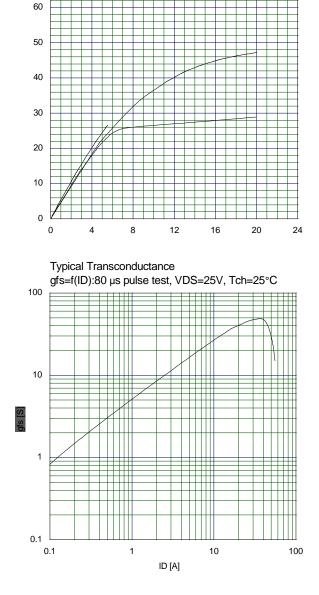
Description	Symbol	Characteristics	Unit	Remarks
Drain-Source Voltage	VDS	500	V	
Drain-Source voltage	VDSX	500	V	Vgs = -30V
Continuous Drain Current	lo	±23	А	
Pulsed Drain Current	Idp	±92	А	
Gate-Source Voltage	Vgs	±30	V	
Repetitive and Non-Repetitive Maximum Avalanche Current	lar	23	А	Note*1
Non-Repetitive Maximum Avalanche Energy	Eas	767.3	mJ	Note*2
Repetitive Maximum Avalanche Energy	Ear	31.5	mJ	Note*3
Peak Diode Recovery dV/dt	dV/dt	9.3	kV/μs	Note*4
Peak Diode Recovery -di/dt	-di/dt	100	A/µs	Note*5
Maximum Dawar Dissingtion	PD	2.50	W	Ta=25°C
Maximum Power Dissipation		315	vv	Tc=25°C
Operating and Storage	Tch	150	°C	
Temperature range	Tstg	-55 to + 150	°C	

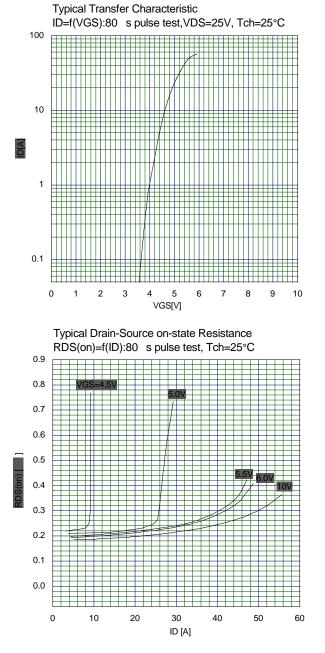
#### • Electrical Characteristics at Tc=25°C (unless otherwise specifed)

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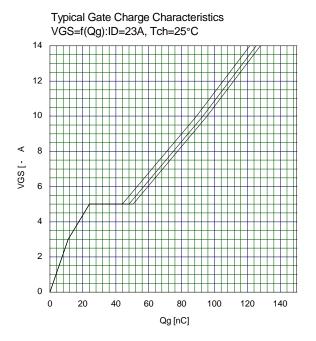
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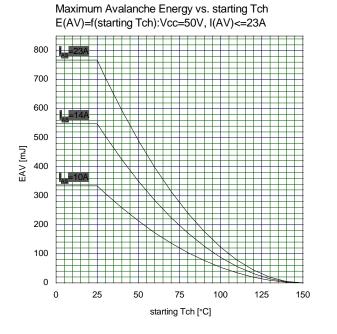


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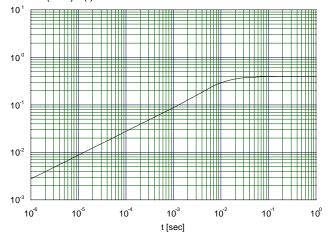
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Maximum Transient Thermal Impedance Zth(ch-c)=f(t):D=0

Zth(ch-c) [°C/W]



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faulty. When usin the equipment from	g Fuji Electric semiconducto	fre, or other problem if any of th	ou are requested to take ade	ductor products may become equate safety measures to preven t is recommended to make your
4. The products intro requirements.	oduced in this Catalog are in	tended for use in the following e	electronic and electrical equi	pment which has normal reliabilit
Computers	<ul> <li>OA equipment</li> </ul>	<ul> <li>Communications equipment</li> </ul>	nt (terminal devices)	Measurement equipment
Machine tools	Audiovisual equipment		. ,	Industrial robots etc.
it is imperative to o measures such as becomes faulty.	contact Fuji Electric Co., Ltd. a backup system to prevent	r equipment requiring higher reli to obtain prior approval. When the equipment from malfunction	using these products for su hing even if a Fuji's product	ch equipment, take adequate incorporated in the equipment
	quipment (mounted on cars a	and ships)	<ul> <li>Trunk communication</li> </ul>	
• Traffc-signal cor			5	rs with an auto-shut-off feature
<ul> <li>Emergency equip Medical equipme</li> </ul>		sters and anti-burglary devices	<ul> <li>Safety devices</li> </ul>	
6. Do not use produ (without limitation)		uipment requiring strict reliabilit	y such as the following and o	equivalents to strategic equipmer
<ul> <li>Space equipment</li> </ul>	t	<ul> <li>Aeronautic equipment</li> </ul>	<ul> <li>Nuclear control equip</li> </ul>	oment
<ul> <li>Submarine repeating</li> </ul>	ater equipment			
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